EMIF06-mSD01F2

Mini and micro SD Card - EMI filtering and 25 kV ESD protection

Main application
Mini and micro (T-Flash) Secure Digital memory card in mobile phones and communication systems

Description
The EMIF06-mSD01F2 is a highly integrated device based on IPAD technology with the following functions:
■ ESD protection to comply with IEC standard
■ EMI Filtering to reject mobile phone frequencies

Benefits
■ EMI Low-pass-filter
■ ESD protection ±25 kV (IEC 61000-4-2)
■ Integrated pull up resistors to prevent bus floating when no card is connected
■ 50 Mhz clock frequency compatibility with $C_{line} < 20 \, \text{pF}$
■ Low power consumption
■ Easy Layout thanks to smart pin-out configuration
■ Very low PCB space consuming
■ High reliability offered by monolithic integration
■ Reduction of parasitic elements thanks to CSP integration
■ Lead free package
■ Coated version option upon request

Complies with the following standards:
IEC 61000-4-2 level 4 15 kV (air discharge)
8 kV (contact discharge)
MIL STD 883G - Method 3015-7 Class 3A
SD Card Specification Ver. 1.01
MicroSD Card Specification Ver. 1.0
Physical layer specification, Part 1 version 1.1

Flip-Chip (16 Bumps)

Pin configuration (bump side)

Order code

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Marking</th>
</tr>
</thead>
<tbody>
<tr>
<td>EMIF06-mSD01F2</td>
<td>HJ</td>
</tr>
</tbody>
</table>

TM: IPAD is a trademark of STMicroelectronics
1 Characteristics

Table 1. Absolute ratings (limiting values)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter and test conditions</th>
<th>Value</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{PP}$</td>
<td>ESD discharge IEC 61000-4-2, air discharge</td>
<td>25</td>
<td>kV</td>
</tr>
<tr>
<td></td>
<td>ESD discharge IEC 61000-4-2, contact discharge</td>
<td>25</td>
<td>kV</td>
</tr>
<tr>
<td>$V_{in}$</td>
<td>Maximum input voltage</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>$T_J$</td>
<td>Maximum junction temperature</td>
<td>125</td>
<td>°C</td>
</tr>
<tr>
<td>$T_{op}$</td>
<td>Operating temperature range</td>
<td>-40 to +85</td>
<td>°C</td>
</tr>
<tr>
<td>$T_{stg}$</td>
<td>Storage temperature range</td>
<td>125</td>
<td>°C</td>
</tr>
</tbody>
</table>

Figure 1. EMIF06-mSD01F2 configuration

Table 2. Electrical characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Test conditions</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{BR}$</td>
<td>$I_R = 1$ mA</td>
<td>14</td>
<td>16</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>$I_{RM}$</td>
<td>$V_{RM} = 3$ V</td>
<td></td>
<td></td>
<td>0.1</td>
<td>μA</td>
</tr>
<tr>
<td>R1, R2, R3, R4, R5, R6</td>
<td>Tolerance ±20%</td>
<td>40</td>
<td></td>
<td></td>
<td>Ω</td>
</tr>
<tr>
<td>R9, R10, R11, R12, R13</td>
<td>Tolerance ±30%</td>
<td>25</td>
<td></td>
<td></td>
<td>kΩ</td>
</tr>
<tr>
<td>$C_{line}$</td>
<td>$V = 0$ V, $F = 1$ MHz $V_{osc} = 30$ mV</td>
<td>17</td>
<td>20</td>
<td></td>
<td>pF</td>
</tr>
</tbody>
</table>
Figure 2. Frequency response for line D3/D2 - $V_{CC}$ not connected

Figure 3. Frequency response for line C1/B4 - $V_{CC}$ not connected

Figure 4. ESD response to IEC 61000-4-2 (+15 kV air discharge) on one input ($V_{in}$) and one output ($V_{out}$)

Figure 5. ESD response to IEC 61000-4-2 (-15 kV air discharge) on one input ($V_{in}$) and one output ($V_{out}$)

Figure 6. Junction capacitance versus reverse applied voltage CLK line (typical values)
2 Technical information

Figure 7. T-Flash connection diagram recommendation
(MicroSD Specification Ver 1.0)

Pull-up resistance $R_{DAT}$ and $R_{CMD}$ are implemented to prevent bus floating when no card is
inserted or when all card drivers are in high impedance mode. Resistance values should be
set between 10 kΩ and 100 kΩ.

The pull-up resistors and capacitors described in the above recommendation are integrated
in the EMIF06-mSD01F2. This makes the EMIF06-mSD01F2 an easy "plug and play"
solution to implement secured T-flash, mini-SD card terminations.

Figure 8. Layout recommendation
3 Ordering information scheme

EMIF yy - xxx zz Fx

EMI Filter

Number of lines

Information
x = resistance value (Ohms)
z = capacitance value / 10(pF)
or
3 letters = application
2 digits = version

Package
F = Flip-Chip
x = 2: Lead free Pitch = 500 µm, Bump = 315 µm

4 Package information

Figure 9. Flip-Chip Package dimensions

500 µm ± 50
315 µm ± 50
1.92 mm ± 50 µm

Figure 10. Foot print recommendations

Copper pad Diameter: 210 µm recommended, 200 µm max
Solder stencil opening: 350 µm
Solder mask opening recommendation: 340 µm min for 300 µm copper pad diameter

Figure 11. Marking

Dot, ST logo
xx = marking
z = manufacturing location
yw = datecode
(y = year
w = week)
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Note: More packing information is available in the application notes:
AN1235: “Flip-Chip: Package description and recommendations for use”
AN1751: “EMI Filters: Recommendations and measurements”

5 Ordering information

<table>
<thead>
<tr>
<th>Ordering code</th>
<th>Marking</th>
<th>Package</th>
<th>Weight</th>
<th>Base qty</th>
<th>Delivery mode</th>
</tr>
</thead>
<tbody>
<tr>
<td>EMI06-mSD01F2</td>
<td>HJ</td>
<td>Flip-Chip</td>
<td>5.3 mg</td>
<td>5000</td>
<td>Tape and reel 7”</td>
</tr>
</tbody>
</table>

6 Revision history

<table>
<thead>
<tr>
<th>Date</th>
<th>Revision</th>
<th>Description of Changes</th>
</tr>
</thead>
<tbody>
<tr>
<td>02-Feb-2007</td>
<td>1</td>
<td>First issue.</td>
</tr>
</tbody>
</table>